

# New Jersey Semi-Conductor Products, Inc.

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## 2N3456 N-CHANNEL SILICON JUNCTION FIELD-EFFECT TRANSISTORS

### \*ABSOLUTE MAXIMUM RATINGS (25°C)

Gate-Drain or Gate-Source Voltage.....	-50 V
Gate Current.....	10 mA
Total Device Dissipation at (or below) 25°C Free-Air Temperature (Note 1) .....	300 mW
Storage Temperature Range .....	-65 to +200°C
Maximum Operating Temperature .....	200°C

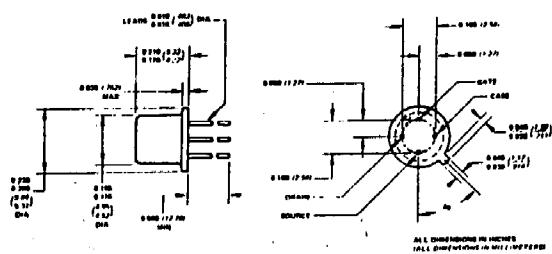
### \*ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

Characteristic	Test Conditions	2N3456		Unit
		Min	Max	
$I_{GSS}$ Gate Reverse Current	$V_{GS} = -30$ V, $V_{DS} = 0$	-0.04	nA	
	25°C			
	150°C	-0.15	μA	
$V_{DGO}$ Drain-Gate Breakdown Voltage	$I_D = 1 \mu A$ , $I_S = 0$	-80		V
$V_P$ Gate-Source Pinch-Off Voltage	$V_{DS} = 20$ V, $I_D = 1 \mu A$	-4.0		V
$I_{D(OFF)}$ Drain Cutoff Current	$V_{DS} = 20$ V, $V_{GS} = (-)$	0.5 (-8.0)	nA (V)	
$I_{D(0)}$ Drain Current at Zero Gate Voltage	$V_{DS} = 30$ V (Note 2), $V_{GS} = 0$	0.2	1.0	mA
$\mu_{fs}$ Small-Signal Common-Source Forward Transconductance	$V_{DR} = 30$ V (Note 3), $V_{GS} = 0$ , $f = 1$ MHz	300	800	μmho
$\mu_{oss}$ Small-Signal Common-Source Output Conductance	$V_{DR} = 30$ V, $V_{GS} = 0$ , $f = 1$ MHz	8		μmho
$C_{oss}$ Common-Source Output Capacitance (Input Shorted)	$V_{DS} = 30$ V, $V_{GS} = 0$ , $f = 1$ MHz	1.5		pF
$C_{iss}$ Common-Source Input Capacitance (Output Shorted)	$V_{GS} = 0$ , $f = 1$ MHz, $V_{DS} = (-)$	8 (8)		pF (V)
NF Noise Figure	$V_{DS} = 10$ V, $V_{GS} = 0$ , $f = (-)$ , $R_{gen} = 1$ meg, $BW = 6$ Hz	4 (20)		dB (Hz)

#### NOTES:

1. Derate linearly to 150°C free-air temperature at rate of 1.7 mW/°C.
2. To minimize heating on high  $I_{DSS}$  units, this parameter is measured during a 2 ms interval 100 ms after power is applied. (Not a JEDEC condition.)

\*JEDEC registered data.



JEDEC TO-72  
Fourth lead is in electrical contact with case.

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